New Product

VBT2045CBP

Vishay General Semiconductor

Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low $V_F = 0.33$ V at $I_F = 5.0$ A

TMBS®

2 x 10 A

45 V

160 A

0.41 V

150 °C

TO-263AB



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF Ro maximum peak of 245 °C
 - COMPLIANT
- Not recommended for PCB bottom side wave mounting
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

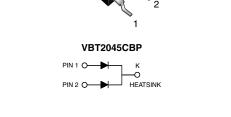
Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | |
|---|------------|--|-------|------|--|
| PARAMETER | | SYMBOL VBT2045CBP | | UNIT | |
| Maximum repetitive peak reverse voltage | | V _{RRM} | 45 | V | |
| Maximum average forward rectified current (fig. 1) | per device | I _{F(AV)} ⁽¹⁾ | 20 | ^ | |
| | per diode | | 10 | A | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | | I _{FSM} | 160 | А | |
| Operating junction and storage temperature range | | T _{OP} , T _{STG} - 40 to + 150 | | °C | |
| Junction temperature in DC forward current without reverse bias, t \leq 1 h | | T _J ⁽²⁾ | ≤ 200 | °C | |

Notes

(1) With heatsink

⁽²⁾ Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test



PRIMARY CHARACTERISTICS

I_{F(AV)}

V_{RRM}

I_{FSM}

 V_F at $I_F = 10 A$

T_{OP} max.

VBT2045CBP





| ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | | | |
|---|----------------------------|---------------------------|---------------------------------|------|------|------|--|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT | |
| Instantaneous forward voltage per diode | I _F = 5 A | T _A = 25 °C | - V _F ⁽¹⁾ | 0.44 | - | V | |
| | I _F = 10 A | | | 0.49 | 0.58 | | |
| | I _F = 5 A | - T _A = 125 °C | | 0.33 | - | | |
| | I _F = 10 A | | | 0.41 | 0.52 | | |
| Reverse current per diode | $V_{\rm B} = 45 \text{ V}$ | T _A = 25 °C | I _R ⁽²⁾ | - | 2000 | μA | |
| | | T _A = 125 °C | | 10 | 30 | mA | |

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

| THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | | |
|--|------------|-----------------------|------------|------|--|--|
| PARAMETER | | SYMBOL | VBT2045CBP | UNIT | | |
| Typical thermal resistance | per diode | $R_{	extsf{	heta}JC}$ | 3.0 | °C/W | | |
| rypical themai resistance | per device | | 2.0 | C/W | | |

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|------------------|-----------------|--------------|---------------|---------------|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | |
| TO-263AB | VBT2045CBP-E3/4W | 1.38 | 4W | 50/tube | Tube | |
| TO-263AB | VBT2045CBP-E3/8W | 1.38 | 8W | 800/reel | Tape and reel | |

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

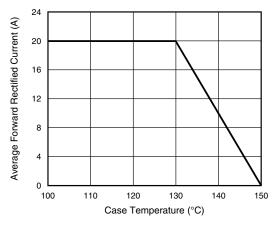


Fig. 1 - Maximum Forward Current Derating Curve

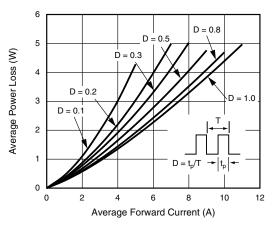


Fig. 2 - Forward Power Loss Characteristics Per Diode



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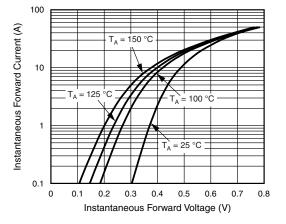


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

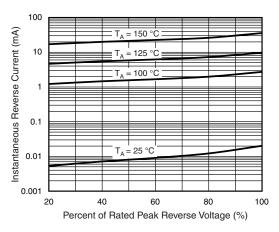


Fig. 4 - Typical Reverse Characteristics Per Diode

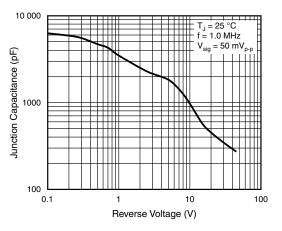


Fig. 5 - Typical Junction Capacitance Per Diode

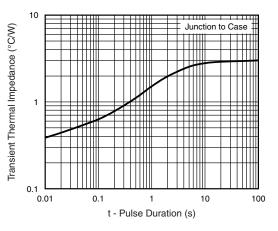


Fig. 6 - Typical Transient Thermal Impedance Per Diode

TO-263AB 0.411 (10.45) 0.190 (4.83) **Mounting Pad Layout** 0.380 (9.65) 0.055 (1.40) 0.160 (4.06) 0.42 (10.66) MIN. 0.245 (6.22) 0.045 (1.14) MIN. 0.055 (1.40) 0.33 (8.38) MIN. 0.360 (9.14) 0.047 (1.19) 0.320 (8.13) 0.624 (15.85) K 2 0.591 (15.00) 0.670 (17.02) 0 to 0.01 (0 to 0.254) 0.591 (15.00) 0.110 (2.79) 0.110 (-0.090 (2.29) 0.037 (0.940) 0.15 (3.81) MIN. 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56) 0.08 (2.032) MIN. 0.095 (2.41) 0.205 (5.20) 0.110 (2.79) 0.195 (4.95) 0.105 (2.67) 0.095 (2.41)

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

For technical questions within your region, please contact one of the following: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com



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